Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal Overall Length:

0.505 inches

**Mounting Facility Quantity:** 

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.562 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 breakover voltage, dc

Current Rating Per Characteristic:

900.00 amperes forward current, average absolute

**Power Rating Per Characteristic:** 

500.0 milliwatts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius case

**Special Features:** 

Internal junction configuration arrangement npnp

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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**Demilitarization:** 

No

Fiig:

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